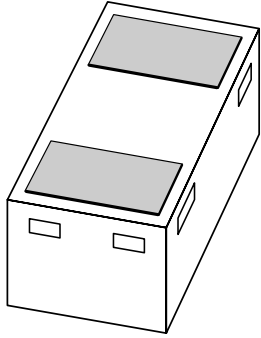


# DATA SHEET



## **1PS10SB82** Schottky barrier diode

Product data sheet

2003 Aug 20

# Schottky barrier diode

# 1PS10SB82

## FEATURES

- Low forward voltage
- Low diode capacitance
- Leadless ultra small plastic package (1.0 mm × 0.6 mm × 0.5 mm)
- Boardspace 1.17 mm<sup>2</sup> (approx. 10% of SOT23)
- Power dissipation comparable to SOT23.

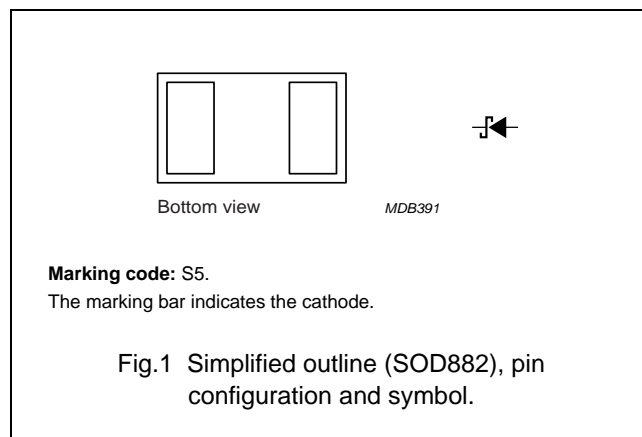
## APPLICATIONS

- UHF mixers
- Sampling circuits
- Modulators
- Phase detectors
- Mobile communication, digital (still) cameras, PDA's and PCMCIA cards.

## DESCRIPTION

An epitaxial Schottky barrier diode encapsulated in a SOD882 leadless ultra small plastic package.

ESD sensitive device, observe handling precautions.



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL           | PARAMETER                  | MIN. | MAX. | UNIT |
|------------------|----------------------------|------|------|------|
| V <sub>R</sub>   | continuous reverse voltage | –    | 15   | V    |
| I <sub>F</sub>   | continuous forward current | –    | 30   | mA   |
| T <sub>stg</sub> | storage temperature        | –65  | +150 | °C   |
| T <sub>j</sub>   | junction temperature       | –    | 150  | °C   |

## Schottky barrier diode

1PS10SB82

**ELECTRICAL CHARACTERISTICS** $T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

| SYMBOL | PARAMETER                             | CONDITIONS                                       | TYP. | MAX. | UNIT          |
|--------|---------------------------------------|--|------|------|---------------|
| $V_F$  | forward voltage                       | see Fig.2  |      |      |               |
|        |                                       | $I_F = 1\text{ mA}$                              | –    | 340  | mV            |
|        |                                       | $I_F = 30\text{ mA}$                             | –    | 700  | mV            |
| $r_D$  | differential diode forward resistance | $f = 1\text{ MHz}; I_F = 5\text{ mA};$ see Fig.5 | 12   | –    | $\Omega$      |
| $I_R$  | continuous reverse current            | $V_R = 1\text{ V};$ see Fig.3; note 1            | –    | 0.2  | $\mu\text{A}$ |
| $C_d$  | diode capacitance                     | $V_R = 0\text{ V}; f = 1\text{ MHz};$ see Fig.4  | 1    | –    | pF            |

**Note**

1. Pulse test:  $t_p = 300\text{ }\mu\text{s}; \delta = 0.02.$

**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1     | 500   | K/W  |

**Note**

1. Refer to SOD882 standard mounting conditions (footprint), FR4 with  $60\text{ }\mu\text{m}$  copper strip line.

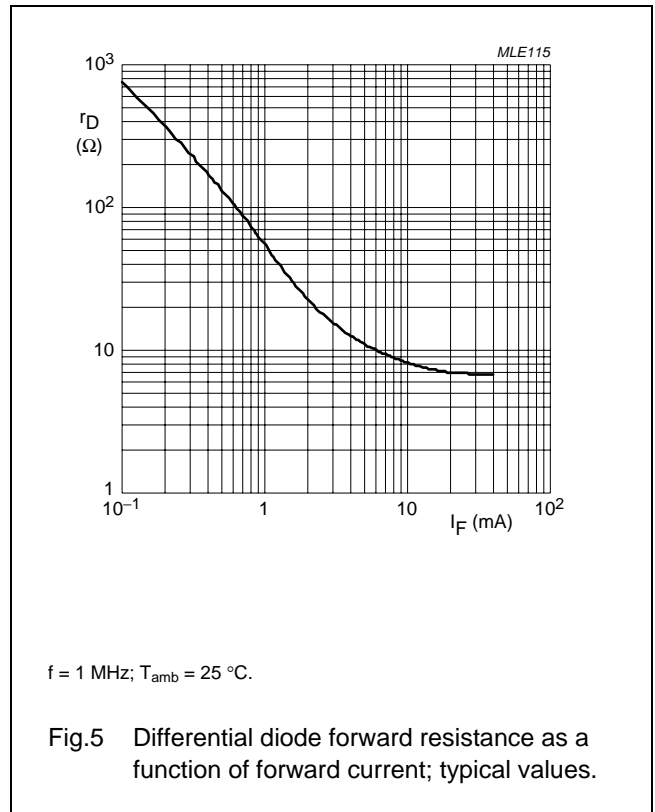
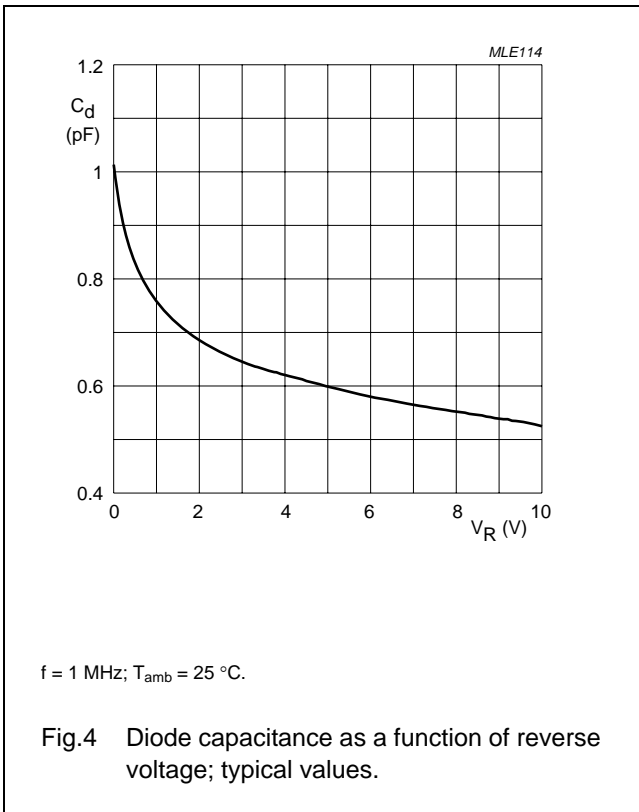
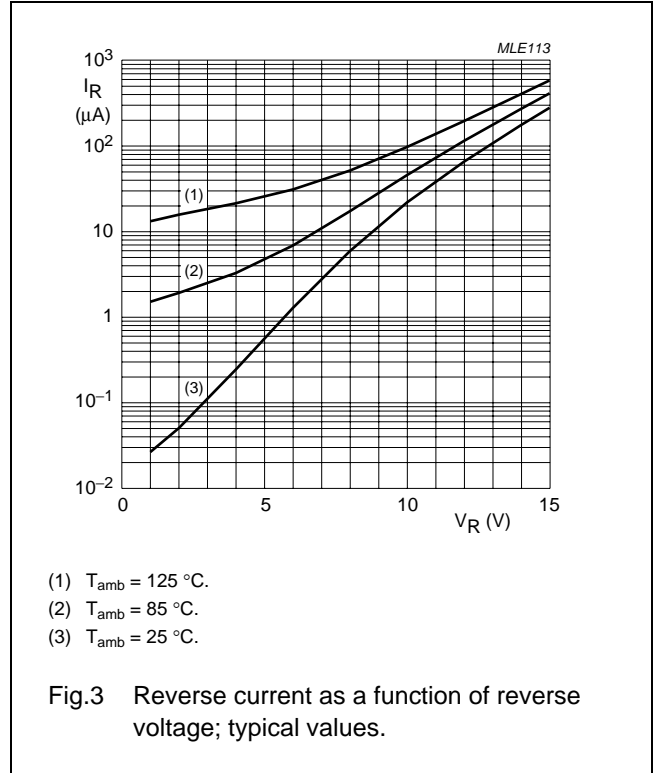
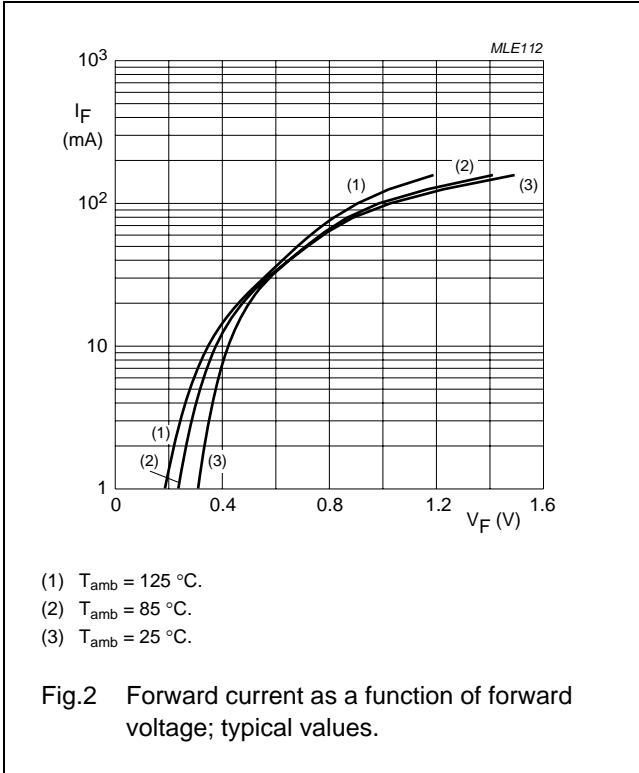
**Soldering**

Reflow soldering is the only recommended soldering method.

Schottky barrier diode

1PS10SB82

GRAPHICAL DATA



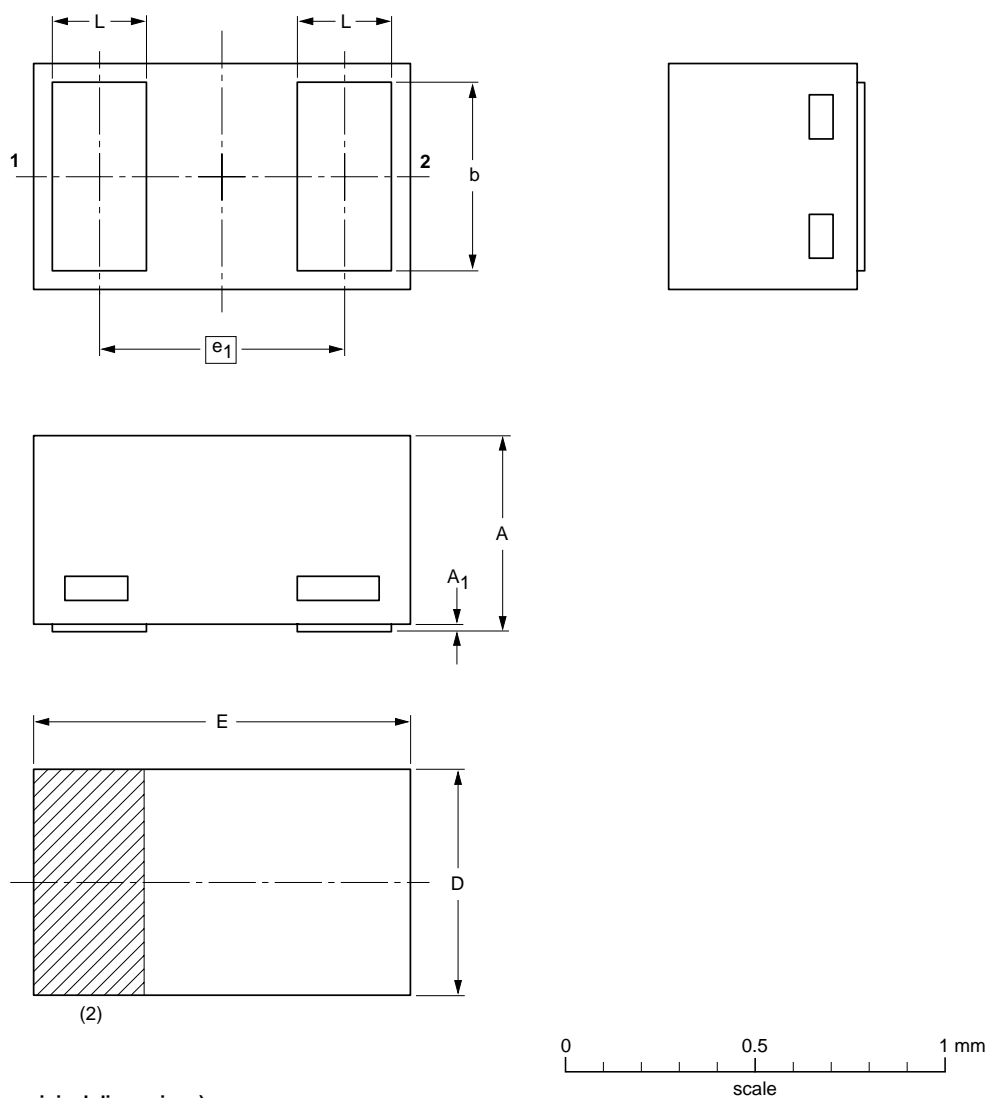
# Schottky barrier diode

# 1PS10SB82

## PACKAGE OUTLINE

Leadless ultra small plastic package; 2 terminals; body 1.0 x 0.6 x 0.5 mm

SOD882



**DIMENSIONS (mm are the original dimensions)**

| UNIT | A <sup>(1)</sup> | A <sub>1</sub><br>max. | b            | D            | E            | e <sub>1</sub> | L            |
|------|------------------|------------------------|--------------|--------------|--------------|----------------|--------------|
| mm   | 0.50<br>0.46     | 0.03                   | 0.55<br>0.47 | 0.62<br>0.55 | 1.02<br>0.95 | 0.65           | 0.30<br>0.22 |

**Notes**

- 1. Including plating thickness
- 2. The marking bar indicates the cathode

| OUTLINE VERSION | REFERENCES |       |       |  | EUROPEAN PROJECTION | ISSUE DATE           |
|-----------------|------------|-------|-------|--|---------------------|----------------------|
|                 | IEC        | JEDEC | JEITA |  |                     |                      |
| SOD882          |            |       |       |  |                     | 03-04-16<br>03-04-17 |

## Schottky barrier diode

1PS10SB82

## DATA SHEET STATUS

| DOCUMENT STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)</sup> | DEFINITION  |
|--------------------------------|-------------------------------|---|
| Objective data sheet           | Development                   | This document contains data from the objective specification for product development. |
| Preliminary data sheet         | Qualification                 | This document contains data from the preliminary specification.                       |
| Product data sheet             | Production                    | This document contains the product specification.                                     |

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